1N4001thru 1N4007

 $I_0 = 1 \text{ AMP}$ V_R — to 1000 V



Low-current, glass passivated silicon rectifiers in subminiature void-free, flame-proof silicone polymer case. Designed to operate under military environmental conditions.

ABSOLUTE MAXIMUM RATINGS (At 60 cps Sinusoidal, Input, Resistive or Inductive Load)

Rating	Symbol	1N4001	1N4C02	1N4003	1N4004	1N4805	1N4006	1N4007	Unit
Peak Repetitive Reverse Voltage DC Blocking Voltage	V _{RM(rep)} V _R	50	100	200	400	600	800	1000	Volts
RMS Reverse Voltage	v _r	35	70	140	280	420	560	700	Volts
Average Half-Wave Rectified Forward Current (75°C Ambient) (100°C Ambient)	Io	1000 750	1000 750	1000 750	1000 750	1000 750	1000 750	1000 750	mA mA
Peak Surge Current 25°C (1/2 Cycle Surge, 60 cps) Peak Repetitive Forward Current	I _{FM(surge)} I _{FM(rep)}	30 10	30 10	30 10	30 10	30 10	30 10	30 10	Amps Amps
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to + 175						°C	

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Rating	Unit Volts	
Maximum Forward Voltage Drop (1 Amp Continuous DC, 25°C)	$v_{\mathbf{F}}$	1, 1		
Maximum Full-Cycle Average Forward Voltage Drop (Rated Current @ 25°C)	V _{F(AV)}	0.8	Volts	
Maximum Reverse Current @ Rated DC Voltage (25°C) (100°C)	IR	0. 01 0. 05	mA	
Maximum Full-Cycle Average Reverse Current (Max Rated PIV and Current, as Half-Wave Rectifier, Resistive Load, 100°C)	I _R (AV)	0. 03	mA	



